TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74LCX245F,TC74LCX245FT,TC74LCX245FK

Low-Voltage Octal Bus Transceiver with 5-V Tolerant Inputs and Outputs

The TC74LCX245 is a high-performance CMOS octal bus transceiver. Designed for use in 3.3-V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

The device is designed for low-voltage (3.3 V) VCC applications, but it could be used to interface to 5-V supply environment for both inputs and outputs.

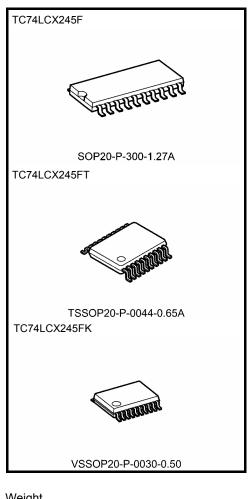
The direction of data transmission is determined by the level of the DIR input. The enable input (\overline{OE}) can be used to disable the device so that the busses are effectively isolated.

All inputs are equipped with protection circuits against static discharge.

Features (Note)

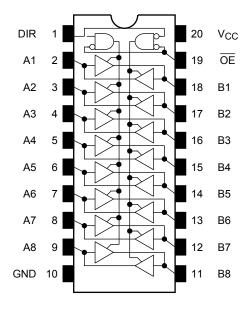
- Low-voltage operation: $V_{CC} = 2.0$ to 3.6 V
- High-speed operation: $t_{pd} = 7.0 \text{ ns} (max) (V_{CC} = 3.0 \text{ to } 3.6 \text{ V})$
- Ouput current: $|I_{OH}|/I_{OL} = 24 \text{ mA} (min) (V_{CC} = 3.0 \text{ V})$
- Latch-up performance: -500 mA
- Available in JEITA SOP, TSSOP and VSSOP (US)
- Bidirectional interface between 5.0 V and 3.3 V signals
- Power-down protection provided on all inputs and outputs
- Pin and function compatible with the 74 series (74AC/VHC/HC/F/ALS/LS etc.) 245 type

Note: Do not apply a signal to any bus pins when it is in the output mode. Damage may result. All floating (high impedance) bus pins must have their input levels fixed by means of pull-up or pull-down resistors.

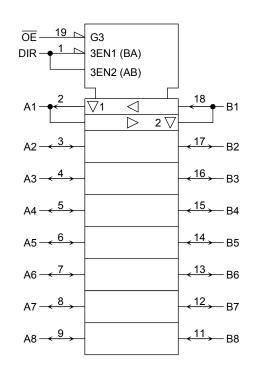


Weight	
SOP20-P-300-1.27A	: 0.22g (typ.)
TSSOP20-P-0044-0.65A	: 0.08 g (typ.)
VSSOP20-P-0030-0.50	: 0.03 g (typ.)

Pin Assignment (top view)



IEC Logic Symbol



Truth Table

Inp	outs	Outputs	Fund	ction
ŌĒ	DIR	Outputs	A-Bus	B-Bus
L	L	A = B	Output	Input
L	Н	B = A	Input	Output
Н	Х	Z	Z	

X: Don't care

Z: High impedance

Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Power supply voltage	V _{CC}	-0.5 to 7.0	V
DC input voltage (DIR, OE)	V _{IN}	-0.5 to 7.0	V
		-0.5 to 7.0 (Note 2)	
DC bus I/O voltage	V _{I/O}	–0.5 to V _{CC} + 0.5	V
		(Note 3)	
Input diode current	I _{IK}	-50	mA
Output diode current	IOK	±50 (Note 4)	mA
DC output current	lout	±50	mA
Power dissipation	PD	180	mW
DC V _{CC} /ground current	I _{CC} /I _{GND}	±100	mA
Storage temperature	T _{stg}	–65 to 150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

- Note 2: Output in OFF state
- Note 3: High or low state. IOUT absolute maximum rating must be observed.

Note 4: $V_{OUT} < GND, V_{OUT} > V_{CC}$

Operating Ranges (Note 1)

Characteristics	Symbol	Rating	Unit		
Power supply voltage	V _{CC} 2.0 to 3.6		V		
Tower suppry voltage	VCC	1.5 to 3.6 (Note 2) V 0 to 5.5 V 0 to 5.5 (Note 3) V 0 to V _{CC} (Note 4) V			
Input voltage (DIR, OE)	V _{IN}	0 to 5.5	V		
Bus I/O voltage	Vuo	0 to 5.5 (Note 3)	V		
Bus i/O voltage	V _{I/O}	0 to V_{CC} (Note 4)	v		
Output current	IOH/IOL	±24 (Note 5)	mA		
Output current	'OH/'OL	ША			
Operating temperature	T _{opr}	-40 to 85	°C		
Input rise and fall time	dt/dv	0 to 10 (Note 7)	ns/V		

- Note 1: The operating ranges are required to ensure the normal operation of the device. Unused inputs and bus inputs must be tied to either VCC or GND. Please connect both bus inputs and the bus outputs with VCC or GND when the I/O of the bus terminal changes by the function. In this case, please note that the output is not short-circuited.
- Note 2: Data retention only
- Note 3: Output in OFF state
- Note 4: High or low state
- Note 5: $V_{CC} = 3.0$ to 3.6 V
- Note 6: $V_{CC} = 2.7$ to 3.0 V
- Note 7: $V_{IN} = 0.8$ to 2.0 V, $V_{CC} = 3.0$ V

Electrical Characteristics

DC Characteristics (Ta = -40 to 85°C)

Character	istics	Symbol	Test Condition		V _{CC} (V)	Min	Max	Unit
	H-level	VIH	-		2.7 to 3.6	2.0	_	
Input voltage	L-level	VIL	-	_	2.7 to 3.6	_	0.8	V
				I _{OH} = -100 μA	2.7 to 3.6	V _{CC} - 0.2		
	H-level	VOH	$V_{IN} = V_{IH} \text{ or } V_{IL}$	$I_{OH} = -12 \text{ mA}$	2.7	2.2	_	
				I _{OH} = -18 mA	3.0	2.4	_	V
Output voltage			I _{OH} = -24 mA	I _{OH} = -24 mA	3.0	2.2	_	
				I _{OL} = 100 μA	2.7 to 3.6	_	0.2	
	L-level	Max		$I_{OL} = 12 \text{ mA}$	2.7	_	0.4	
	L-level	V _{OL}	$V_{IN} = V_{IH} \text{ or } V_{IL}$	$I_{OL} = 16 \text{ mA}$	3.0	_	0.4	
				I _{OL} = 24 mA	3.0	_	0.55	
Input leakage currer	nt	I _{IN}	$V_{IN} = 0$ to 5.5 V		2.7 to 3.6	_	±5.0	μA
3-state output OFF	state current	I _{OZ}	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = 0 \text{ to } 5.5 \text{ V}$		2.7 to 3.6		±5.0	μA
Power-off leakage c	urrent	IOFF	V _{IN} /V _{OUT} = 5.5 V		0		10.0	μA
Ouissesst suggly s			$V_{IN} = V_{CC}$ or GND		2.7 to 3.6		10.0	
Quiescent supply cu	Inent	ICC	V _{IN} /V _{OUT} = 3.6 to 5.5 V		2.7 to 3.6	_	±10.0	μA
Increase in I _{CC} per	input	Δlcc	$V_{IH} = V_{CC} - 0.6 V$		2.7 to 3.6		500	

AC Characteristics (Ta = -40 to 85°C)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Min	Max	Unit
Propagation delay time	t _{pLH}	Figure 1, Figure 2	2.7	_	8.0	ns
i ropagation delay time	t _{pHL}		$\textbf{3.3}\pm\textbf{0.3}$	1.5	7.0	115
Output enable time	t _{pZL}	Figure 1, Figure 3	2.7	—	9.5	ns
	t _{pZH}		$\textbf{3.3}\pm\textbf{0.3}$	1.5	8.5	
Output disable time	t _{pLZ}	Figure 1, Figure 3	2.7	_	8.5	ns
	t _{pHZ}		$\textbf{3.3}\pm\textbf{0.3}$	1.5	7.5	115
Output to output skew	t _{osLH}	(Note)	2.7	_	_	ns
	t _{osHL}	(Note)	$\textbf{3.3}\pm\textbf{0.3}$	_	1.0	115

Note: Parameter guaranteed by design.

 $(t_{\text{OSLH}} = |t_{\text{pLHm}} - t_{\text{pLHn}}|, t_{\text{OSHL}} = |t_{\text{pHLm}} - t_{\text{pHLn}}|)$

Dynamic Switching Characteristics (Ta = 25°C, input: $t_r = t_f = 2.5 \text{ ns}$, $C_L = 50 \text{ pF}$, $R_L = 500 \Omega$)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Тур.	Unit
Quiet output maximum dynamic V _{OL}	V _{OLP}	$V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$	3.3	0.8	V
Quiet output minimum dynamic V _{OL}	V _{OLV}	$V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$	3.3	0.8	V

Capacitive Characteristics (Ta = 25°C)

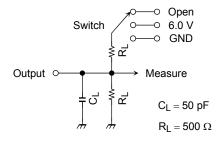
Characteristics	Symbol	Test Condition	V _{CC} (V)	Тур.	Unit
Input capacitance	C _{IN}	DIR, OE	3.3	7	pF
Bus input capacitance	C _{I/O}	An, Bn	3.3	8	pF
Power dissipation capacitance	C _{PD}	f _{IN} = 10 MHz (No	e) 3.3	25	pF

Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption.

Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/8$ (per bit)

AC Test Circuit



Parameter	Switch
t _{pLH} , t _{pHL}	Open
t _{pLZ} , t _{pZL}	6.0 V
t _{pHZ} , t _{pZH}	GND

Figure 1

AC Waveform

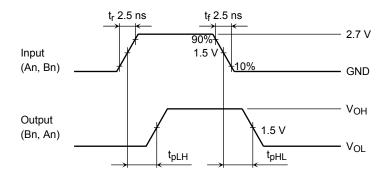


Figure 2 tpLH, tpHL

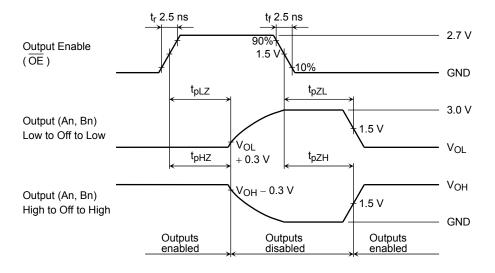


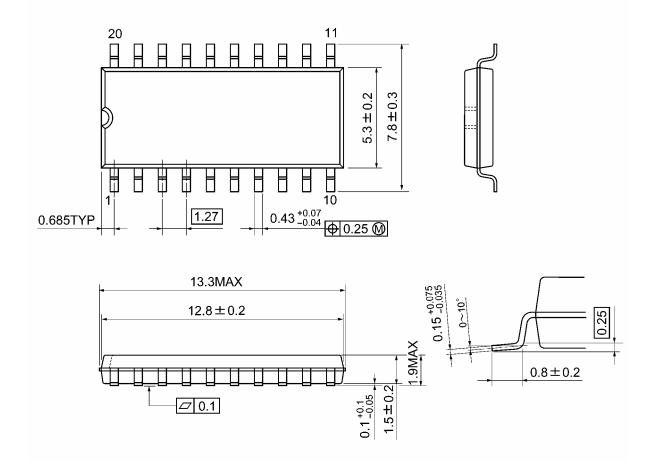
Figure 3 $t_{pLZ}, t_{pHZ}, t_{pZL}, t_{pZH}$



Package Dimensions

SOP20-P-300-1.27A

Unit: mm

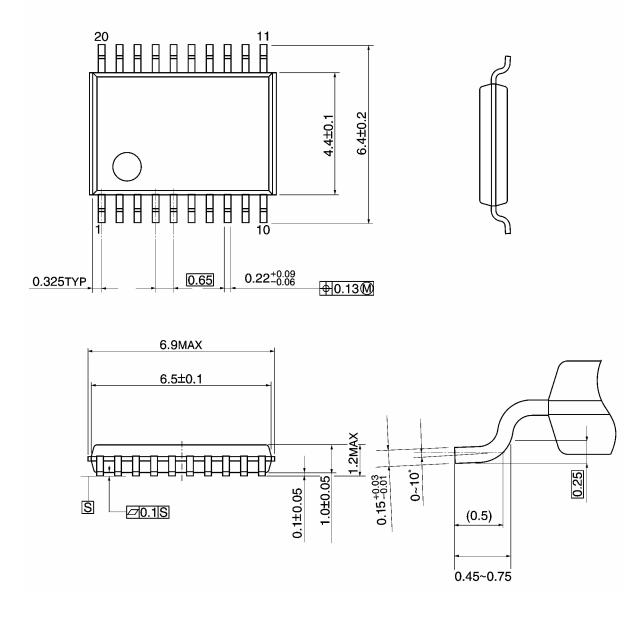


Weight: 0.22 g (typ.)

Package Dimensions

TSSOP20-P-0044-0.65A

Unit: mm

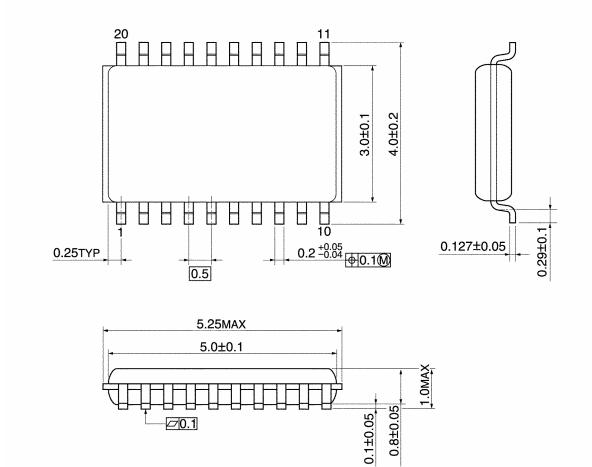


Weight: 0.08 g (typ.)

Package Dimensions

VSSOP20-P-0030-0.50

Unit: mm



Weight: 0.03 g (typ.)

RESTRICTIONS ON PRODUCT USE

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